## NSN 5961-01-306-5476

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-306-5476 **Inclosure Material:** Plastic **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Height:** 0.165 inches **Overall Width:** 0.205 inches **Function For Which Designed:** Voltage reference Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.2 reverse breakdown voltage, dc **Current Rating Per Characteristic:** 30.00 milliamperes reverse current, dc and 10.00 milliamperes forward current, dc **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: